



AP22908

1.5A SINGLE SLEW RATE CONTROLLED LOAD SWITCH

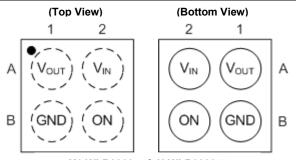
Description

The AP22908 slew rate controlled load switch is a single P-channel MOSFET power switch designed for high-side load-switching applications. The MOSFET has a typical low $R_{DS(ON)}$ of $28m\Omega$ at 3.6V, allowing increased load current handling capacity with a low forward voltage drop. The turn-on slew rate of the device is controlled internally to avoid inrush current.

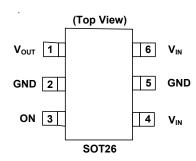
The AP22908 load switch is designed to operate from 1.08V to 3.6V, making it ideal for 1.2V, 1.8V, 2.5V, 3.3V and 3.6V systems. The typical quiescent supply current is only 0.05µA.

The AP22908 is available in the wafer level chip scale 4-pin, X1-WLB0909-4 0.5mm pitch, U-WLB0909-4 0.5mm pitch and standard SOT26 packages.

Pin Assignments



X1-WLB0909-4 & U-WLB0909-4



Features

- Wide Input Voltage Range: 1.08V to 3.6V
- Low On-Resistance:
 - 69mΩ Typical @1.2V
 - 41mΩ Typical @1.8V
 - 33mΩ Typical @2.5V
 - 28mΩ Typical @3.6V
- High DC Current Capability up to 1.5A
- Quick Discharging by Output Discharge Resistance
- Ultra Low Quiescent Current 0.05µA
- Active-High Control Pin
 - Minimum 0.9V VIH of ON
- ESD Protection:
 - Human Body Model: 2kV
 - Charged Device Model: 1kV
- Package:
 - X1-WLB0909-4 with Backside Laminate
 - U-WLB0909-4 with Backside Laminate
 - 0.87mm × 0.87mm, 0.5mm Ball Pitch
 - Standard Green SOT26
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.001 grams (Approximate)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony- Free. "Green" Device (Note 3)

Applications

- Mobile Device and Smart Phones
- Portable Media Devices
- Wearable Devices
- Advanced Notebook, UMPC and MID
- Portable Medical Devices
- **GPS and Navigation Equipment**
- Portable Instrumentation

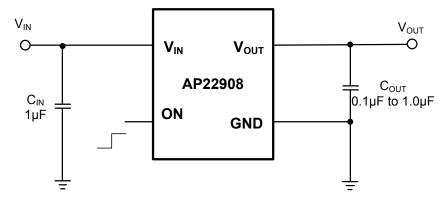
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

1 of 19 AP22908 October 2020 Document number: DS42262 Rev. 3 - 2 © Diodes Incorporated



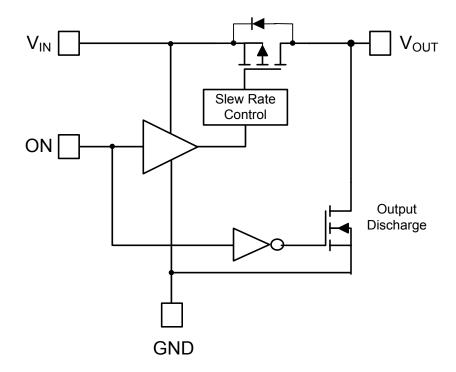
Typical Applications Circuit



Pin Descriptions

Pin Number		n Number	
Pin Name	Pin Name SOT26 X1-WLB0909-4 U-WLB0909-4		Function
V _{OUT}	1	A1	Voltage output pin. This is the pin to the P-channel MOSFET drain connection. Bypass to ground through a $0.1\mu F$ to $1\mu F$ capacitor.
V _{IN}	4, 6	A2	Voltage input pin. This is the pin to the P-channel MOSFET source. Bypass to ground through a 1µF capacitor.
GND	2, 5	B1	Ground
ON	3	B2	Enable input, active high

Functional Block Diagram





Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Ratings	Ratings	
ESD HBM	Human Body Model ESD Protection	2		kV
ESD CDM	Charged Device Model ESD Protection	1		kV
V_{IN}	Input Voltage	-0.3 to 4	+	V
V _{OUT}	Output Voltage	-0.3 to 4		V
V _{ON}	ON Voltage	-0.3 to 4		V
I _{OUT}	Maximum Continuous Output Current (V _{IN} □1.2V)	1.5		Α
I _{OUT}	Maximum Pulse Output Current, Pulse <300µs, 2% Duty Cycle	2.5		Α
T_J	Maximum Junction Temperature	+125	+125	
T _{STG}	Storage Temperature Range	-65 to +15	-65 to +150	
P _D	Power Dissipation	X1-WLB0909-4 U-WLB0909-4	735	mW
		SOT26	606	mW
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Note 4)	X1-WLB0909-4 U-WLB0909-4	136	°C/W
		SOT26	165	°C/W
$R_{ heta JC}$	Thermal Resistance, Junction to Case (Note 5)	X1-WLB0909-4 U-WLB0909-4	31	°C/W
		SOT26	30	°C/W

Notes: 4. The JEDEC high-K (2s2p) board used to derive this data was a 3 inch × 3 inch, multilayer board with 1oz internal power and ground planes with 2oz copper traces on top and bottom of the board.

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability can be affected by exposure to absolute maximum rating conditions for extended periods of time.

Recommended Operating Conditions (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{IN}	Input Voltage	1.08	3.6	V
V_{ON}	ON Voltage Range	0	3.6	V
V _{OUT}	Output Voltage	0	3.6	V
I _{OUT}	Output Current	0	1.5	Α
V _{IH}	ON High-Level Input Voltage	0.9	3.6	V
V _{IL}	ON Low-Level Input Voltage	0	0.38	V
T _A	Operating Ambient Temperature	-40	+85	°C

AP22908 3 of 19
Document number: DS42262 Rev. 3 - 2 Downloaded From Oneyac.com

Thermal resistance from junction to case.



Electrical Characteristics ($T_A = -40^{\circ}C$ to +85°C, $V_{IN} = 1.08V$ to 3.6V, $V_{ON} = V_{IN}$ (enabled), $V_{ON} = 0V$ (disabled), $C_{IN} = 1\mu F$, $C_{OUT} = 0.1\mu F$, typical values are at $T_A = +25^{\circ}C$, unless otherwise specified.) (Note 6)

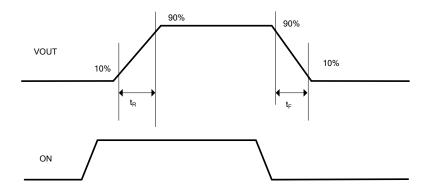
Symbol	Parameters	Test Co	nditions	Min	Тур	Max	Unit
IQ	Input Quiescent Current	$I_{OUT} = 0mA,$ $V_{ON} = V_{IN}(Enabled)$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	_	0.05	1	μΑ
I _{SHDN}	Input Shutdown Current	$R_L = 1M\Omega$, $V_{ON} = Disabled$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	_	0.04	0.5	μА
I _{IN_LEAK}	Input Leakage Current	V _{OUT} = 0V, V _{ON} = Disabled	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	_	0.04	0.5	μА
Ion	ON Input leakage	V_{ON} = 1.1V to 3.6V or V_{ON} = V_{IN}	T _A = -40°C to +85°C	_	0.01	0.1	μΑ
		V _{IN} = 3.6V	T _A = +25°C	_	28	32	
		VIN = 3.6V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	-	_	40	
		V _{IN} = 2.5V	T _A = +25°C	_	33	38	
		VIN = 2.5V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	45	
	X1-WLB0909-4 & U-WLB0909-4 Package,	V _{IN} = 1.8V	T _A = +25°C	_	41	50	mΩ
	Switch On-Resistance, I _{OUT} = -200mA		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	54	
		V _{IN} = 1.2V	T _A = +25°C	_	69	87	
			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	91	
		V _{IN} = 1.08V	T _A = +25°C	_	112	155	
В			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	165	
R _{DS(ON)}		V - 2 6V	T _A = +25°C	_	40	43	
		V _{IN} = 3.6V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	55	
		V = 2.5V	T _A = +25°C	_	45	49	
		V _{IN} = 2.5V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	59	mΩ
	SOT26 Package,	\/ = 1 9\/	T _A = +25°C	_	53	62	
	Switch On-Resistance, I _{OUT} = -200mA	V _{IN} = 1.8V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	69	
		V = 1.2V	T _A = +25°C	_	91	110	
		V _{IN} = 1.2V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	120	
		V = 1.09V	T _A = +25°C	_	120	175	
		V _{IN} = 1.08V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	_	_	185	
R _{DIS}	Discharge FET On-Resistance	$V_{IN} = 3.3V, V_{ON} = 0V, I_{O}$	_{UT} = 30mA, T _A = +25°C	_	80	100	Ω

Notes: 6. Specifications are over -40°C to +85°C and are guaranteed by characterization and design.

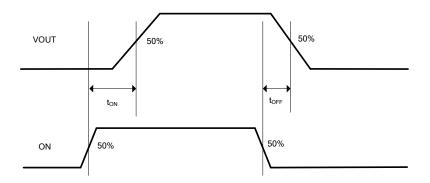


Timing Characteristics (Note 7)

Symbol	Parameters	Test Conditions	Min	Тур	Max	Unit
ton	Output Turn-On Time		1	110	_	μs
toff	Output Turn-Off Time	V 0.0V D 400 0 0.4VE T 1.0500	_	5	_	μs
t _R	Output Rise Time	$V_{IN} = 3.6V$, $R_L = 10\Omega$, $C_{OUT} = 0.1\mu$ F, $T_A = +25$ °C	_	105	_	μs
t_{F}	Output Fall Time		_	2	_	μs
t _{ON}	Output Turn-On Time		_	900	_	μs
toff	Output Turn-Off Time	V = 4.00V D = 400 C = 0.4VE T = 1.25°C	_	5	_	μs
t _R	Output Rise Time	$V_{IN} = 1.08V, R_L = 10\Omega, C_{OUT} = 0.1\mu F, T_A = +25^{\circ}C$	_	442	_	μs
t _F	Output Fall Time			2	_	μs



Output Rise (t_R) and Fall (t_F) Time

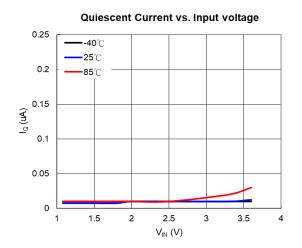


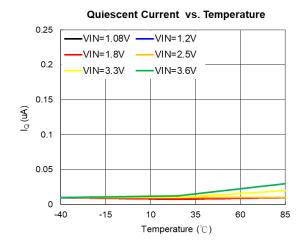
Output Turn On (ton) and Turn Off (toff) time

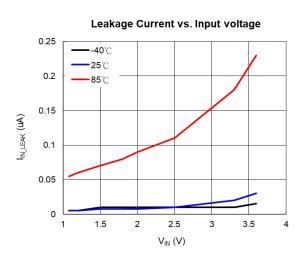
Notes: 7. Rise and fall time of the control signal are less than 100ns.

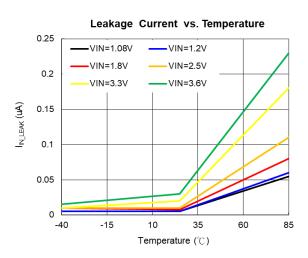


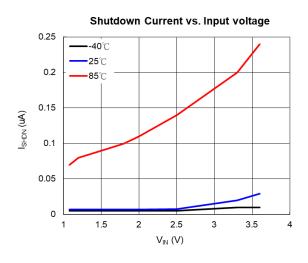
Typical Performance Characteristics ($C_{IN} = 1 \mu F$, $C_{OUT} = 0.1 \mu F$, unless otherwise specified.)

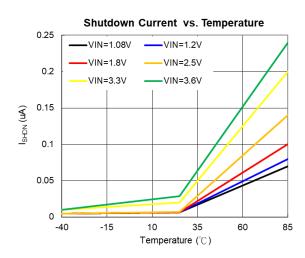






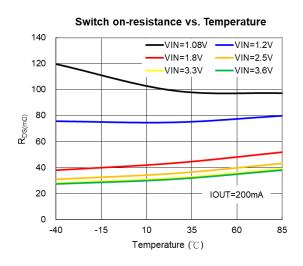


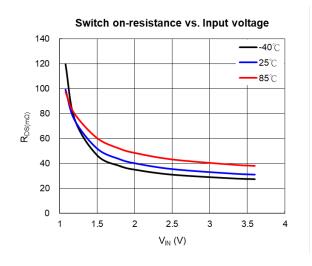


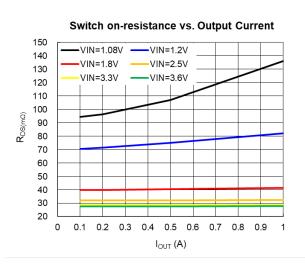


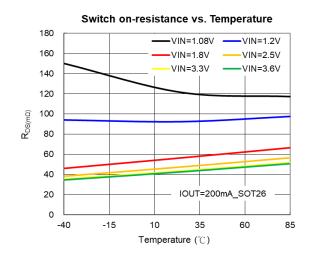


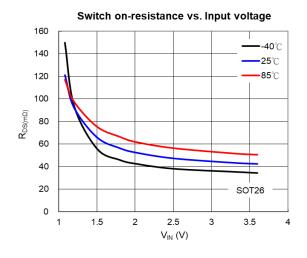
Typical Performance Characteristics ($C_{IN} = 1\mu F$, $C_{OUT} = 0.1\mu F$, unless otherwise specified.)

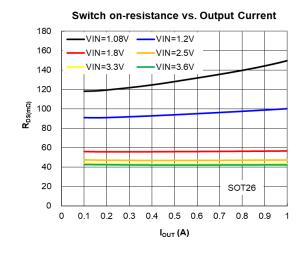






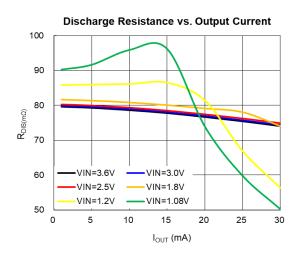


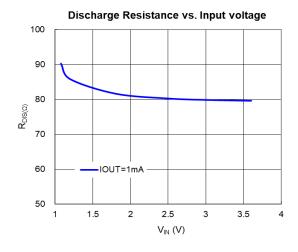




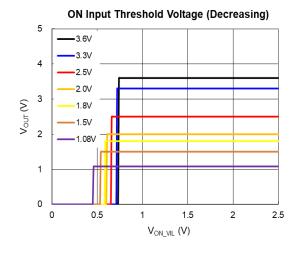


Typical Performance Characteristics ($C_{IN} = 1 \mu F$, $C_{OUT} = 0.1 \mu F$, unless otherwise specified.)



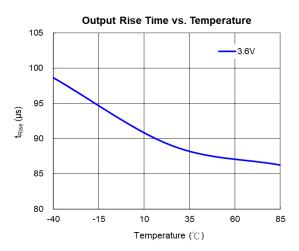


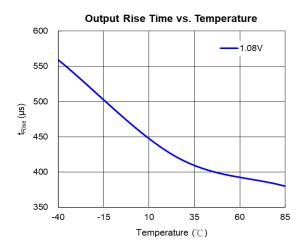
ON Input Threshold Voltage (Increasing) 5 **-**3.6V 3.3V 4 2.5V 2.0V 3 V₀-1 1.5V 2 1.08V 1 0 0 0.5 2.5 $V_{\text{ON_VIH}}$ (V)

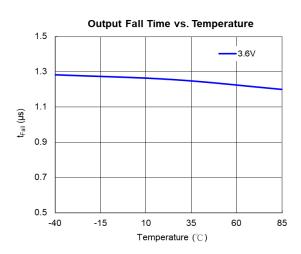


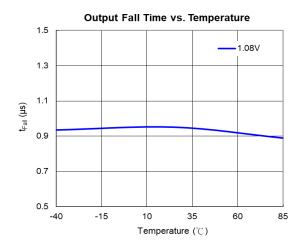


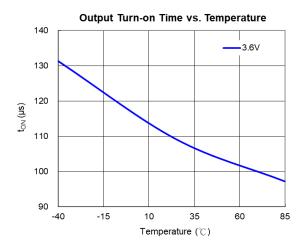
Typical Performance Characteristics ($C_{IN} = 1 \mu F$, $C_{OUT} = 0.1 \mu F$, $R_L = 10 \Omega$, unless otherwise specified.)

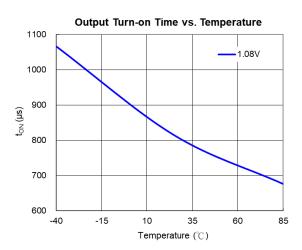






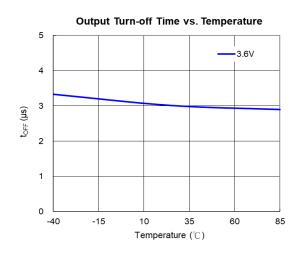


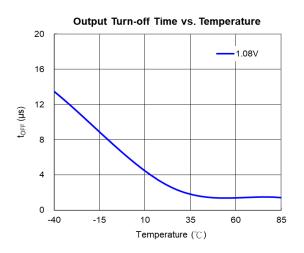


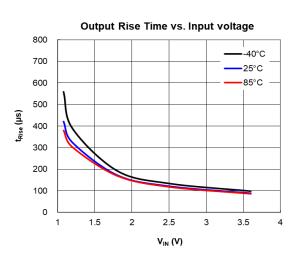


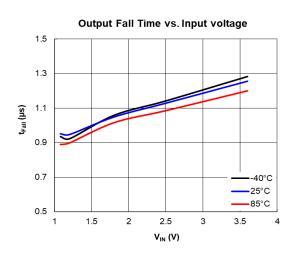


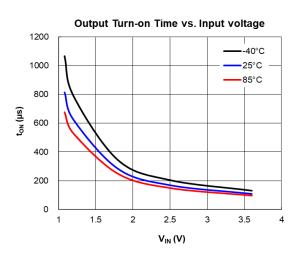
Typical Performance Characteristics ($C_{IN} = 1 \mu F$, $C_{OUT} = 0.1 \mu F$, $R_L = 10 \Omega$, unless otherwise specified.)

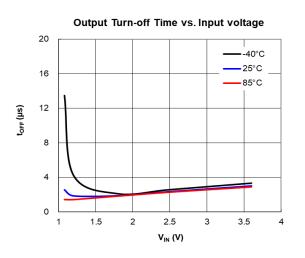






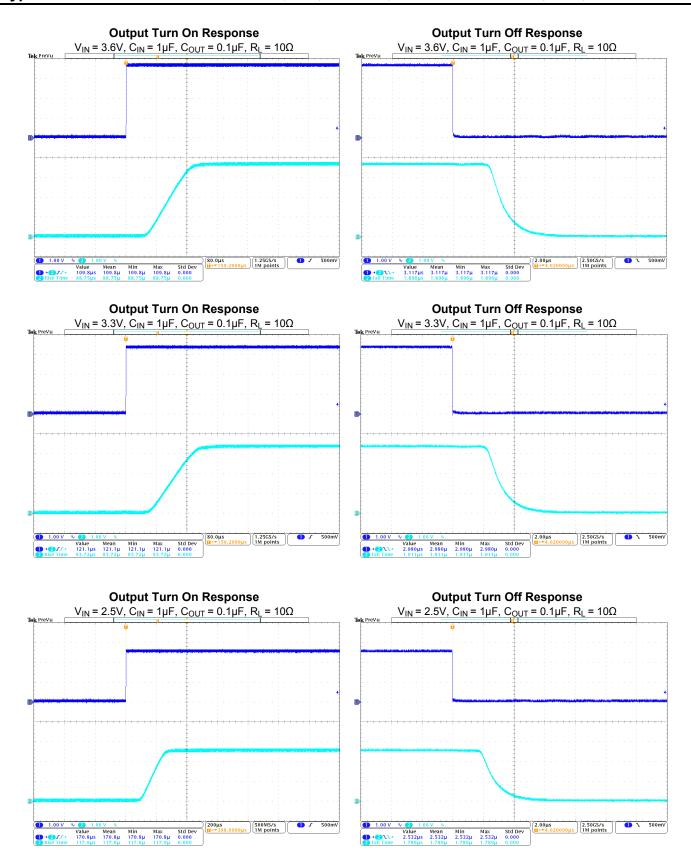






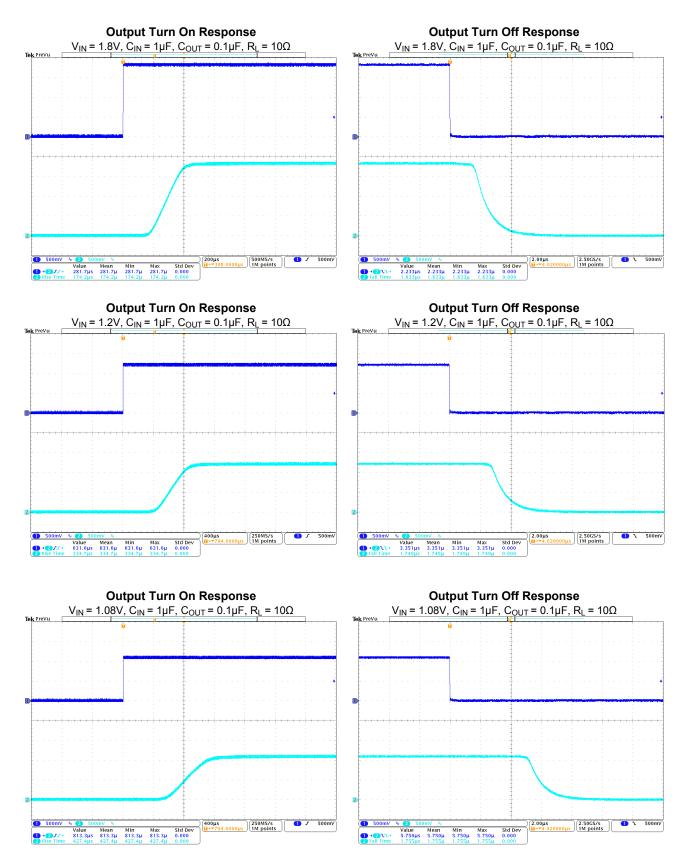


Typical Performance Characteristics (C_{IN} = 1 μ F, C_{OUT} = 0.1 μ F, R_L = 10 Ω , unless otherwise specified.)





Typical Performance Characteristics (C_{IN} = 1 μ F, C_{OUT} = 0.1 μ F, R_L = 10 Ω , unless otherwise specified.)





Application Information

Input Capacitor

A 1µF capacitor is recommended to connect between the VIN and GND pins to decouple input power supply glitch and noise. The input capacitor has no specific type or ESR (Equivalent Series Resistance) requirement. However, for higher current application, ceramic capacitors are recommended due to their capability to withstand input current surges from low impedance sources, such as batteries in portable applications. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both V_{IN} and GND.

Output Capacitor

The 0.1µF to 1µF capacitor is recommended to connect between V_{OUT} and GND pins to stabilize and accommodate load transient condition. The output capacitor has no specific type or ESR requirement. The amount of the capacitance may be increased without limit. For PCB layout, the output capacitor must be placed as close as possible to V_{OUT} and GND pins, and keep the traces as short as possible.

Enable/Shutdown Operation

The AP22908 is turned on by setting the ON pin high, and is turned off by pulling it low. To ensure proper operation, the signal source used to drive the ON pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under VIL and VIH.

Discharge Operation

The AP22908 offers a discharge option that helps discharge the output charge when disabled. The discharge resistance with a typical value of 80Ω is connected between the output and ground.

Power Dissipation

The maximum IC junction temperature should be restricted to +125°C under normal operating conditions. The device power dissipation and proper sizing of the thermal plane is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

$$P_{D} = I_{OLIT}^{2} x R_{DSON}$$
 (1)

However, the maximum power dissipation that can be handled by the device depends on the maximum junction to ambient thermal resistance, maximum ambient temperature, and maximum device junction temperature, which can be approximated by the equation below:

$$P_{D(MAX)} = \frac{(125^{\circ}C - T_A)}{\theta_{JA}}$$
 (2)

Layout Guildline

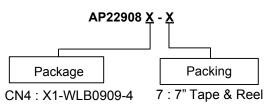
Good PCB layout is important for improving the thermal performance of the device. All trace lengths should be kept as short as possible. The input (V_{IN}) and output (V_{OUT}) PCB traces should be as wide as possible to reduce stray impedance.

Use a ground plane to enhance the power dissipation capability of the device if applicable. Place input and output capacitors close to the device to minimize the effects of parasitic inductance.

13 of 19 AP22908 Document number: DS42262 Rev. 3 - 2



Ordering Information



CNA4: U-WLB0909-4

W6: SOT26

Part Number	Pankaga Codo	Dockoning	7" Tape and Reel		
Part Number	Package Code	Packaging Quantity		Part Number Suffix	
AP22908CN4-7	CN4	X1-WLB0909-4	3,000/Tape & Reel	-7	
AP22908CNA4-7	CNA4	U-WLB0909-4	3,000/Tape & Reel	-7	
AP22908W6-7	W6	SOT26	3,000/Tape & Reel	-7	

Feature Options:

i eature Options.			
Part Number	Rise Time (Typ) at 3.6V	Output Discharge	Enable
AP22908CN4-7	105µs	Yes	Active High
AP22908CNA4-7	105µs	Yes	Active High
AP22908W6-7	105µs	Yes	Active High

AP22908 14 of 19
Document number: DS42262 Rev. 3 - 2 Downloaded From Oneyac.com



Marking Information

(1) X1-WLB0909-4

(Top View)

• X Y W

X: Identification Code

Y: Year: 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week

Part Number	Package	Identification Code
AP22908CN4-7	X1-WLB0909-4	$\overline{4}$

(2) U-WLB0909-4

(Top View)



X: Identification Code

Y: Year: 0~9

W: Week: A~Z: 1~26 week;

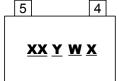
a~z: 27~52 week; z represents

52 and 53 week

Part Number	Package	Identification Code	
AP22908CNA4-7	U-WLB0909-4	8	

(3) SOT25

(Top View)



 \underline{XX} : Identification Code

 \underline{Y} : Year 0 to 9

<u>W</u>: Week: A to Z: 1 to 26 week;

a to z : 27 to 52 week; z represents 52 and 53 week

52 and 53 week Internal Code

1 2 3 <u>X</u>	: Internal Cod
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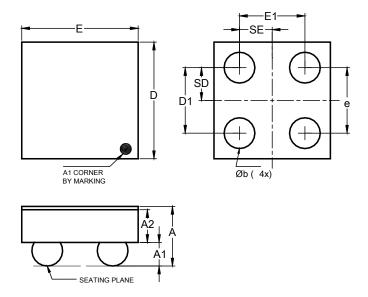
Part Number	Package	Identification Code
AP22908W5-7	SOT25	N8



Package Outline Dimensions

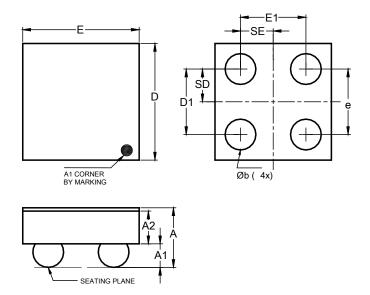
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: X1-WLB0909-4



X1-WLB0909-4						
Dim	Min	Max	Тур			
Α	0.410	0.500	0.455			
A1	0.160	0.200	0.180			
A2	0.225	0.275	0.250			
b	0.215	0.255	0.235			
D	0.840	0.900	0.870			
D1	0.450	0.550	0.500			
Е	0.840	0.900	0.870			
E1	0.450	0.550	0.500			
е	0	.500 BS	С			
SD	0.250 BSC					
SE 0.250 BSC						
All	Dimens	ions in	mm			

(2) Package Type: U-WLB0909-4



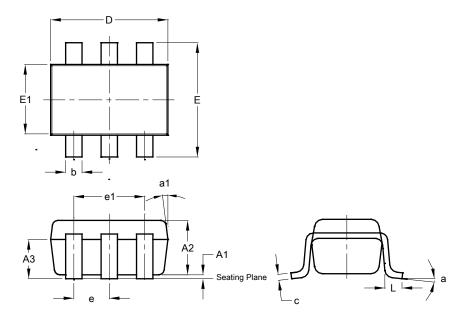
U-WLB0909-4					
Dim	Min	Max	Тур		
Α	0.540	0.630	0.585		
A1	0.160	0.200	0.180		
A2	0.355	0.405	0.380		
b	0.205	0.265	0.235		
D	0.860	0.920	0.880		
D1	0.450	0.550	0.500		
Е	0.860	0.920	0.880		
E1	0.450	0.550	0.500		
е	0.500 BSC				
SD	0.250 BSC				
SE	0.250 BSC				
All Dimensions in mm					



Package Outline Dimensions (Continued)

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$

(3) Package Type: SOT26



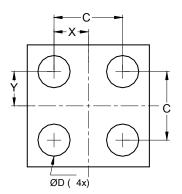
SOT26				
Dim	Min	Max	Тур	
A1	0.013	0.10	0.05	
A2	1.00	1.30	1.10	
A3	0.70	0.80	0.75	
b	0.35	0.50	0.38	
С	0.10	0.20	0.15	
D	2.90	3.10	3.00	
е	-	-	0.95	
e1	_	-	1.90	
Е	2.70	3.00	2.80	
E1	1.50	1.70	1.60	
L	0.35	0.55	0.40	
а	-	-	8°	
a1	-	-	7°	
All Dimensions in mm				



Suggested Pad Layout

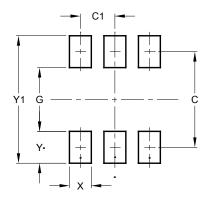
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: X1-WLB0909-4 & U-WLB0909-4



Dimensions	Value	
Dillielisions	(in mm)	
С	0.500	
D	0.235	
Х	0.250	
Y	0.250	

(2) Package Type: SOT26



Dimensions	Value (in mm)	
С	2.40	
C1	0.95	
G	1.60	
Х	0.55	
Y	0.80	
Y1	3 20	



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19 of 19 AP22908 October 2020 © Diodes Incorporated Document number: DS42262 Rev. 3 - 2

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